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S-8353/8354 Series

STEP-UP, PWM CONTROL or PWM / PFM SWITCHABLE BUILT-IN TRANSISTOR SWITCHING REGULATOR

www.sii-ic.com

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Rev.3.0 00

The S-8353/8354 Series is a CMOS step-up switching regulator which mainly consists of a reference voltage source, an oscillation circuit, a power MOS FET, an error amplifier, a phase compensation circuit, a PWM control circuit (S-8353 Series) and a PWM / PFM switching control circuit (S-8354 Series).

The S-8353/8354 Series can configure the step-up switching regulator with an external coil, capacitor, and diode. In addition to the above features, the small package and low current consumption make the S-8353/8354 Series ideal for portable equipment applications requiring high efficiency.

The S-8353 Series realizes low ripple, high efficiency, and excellent transient characteristics due to its PWM control circuit whose duty ratio can be varied linearly from 0% to 83% (from 0% to 78% for 250 kHz models), an excellently designed error amplifier, and phase compensation circuits.

The S-8354 Series features a PWM / PFM switching controller that can switch the operation to a PFM controller with a duty ratio is 15% under a light load to prevent a decline in the efficiency due to the IC operating current.

Features

- Low voltage operation: Startup at 0.9 V min. (I_{OUT} = 1 mA) guaranteed
- Low current consumption : During operation 18.7 $\,\mu\text{A}$ (3.3 V, 50 kHz, typ.)

During shutdown: 0.5 µA (max.)

- Duty ratio : Built-in PWM / PFM switching control circuit (S-8354 Series) 15 % to 83 % (30 kHz and 50 kHz models)
 - 15 % to 78 % (250 kHz models)
- · External parts : Coil, capacitor, and diode
- Output voltage : Selectable in 0.1 V steps between 1.5 V and 6.5 V (for V_{DD} / V_{OUT} separate types) Selectable in 0.1 V steps between 2.0 V and 6.5 V (for other than V_{DD} / V_{OUT} separate types)
- Output voltage accuracy : ±2.4%
- Oscillation frequency : 30 kHz, 50 kHz, and 250 kHz selectable
- Soft start function : 6 ms (50 kHz, typ.)
- Lead-free, Sn 100%, halogen-free^{*1}
- *1. Refer to "
 Product Name Structure" for details.

Applications

- · Power supplies for portable equipment such as digital cameras, electronic notebooks, and PDAs
- · Power supplies for audio equipment such as portable CD / MD players
- · Constant voltage power supplies for cameras, VCRs, and communication devices
- Power supplies for microcomputers

Packages

- SOT-23-3
- SOT-23-5
- SOT-89-3

Block Diagrams

(1) A, C and H Types (Without Shutdown Function)

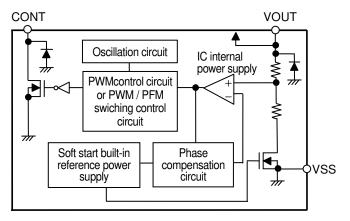
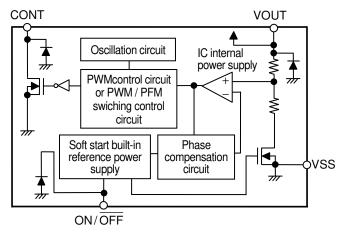


Figure 1

(2) A and H Types (With Shutdown Function)





(3) D and J Types (V_{DD} / V_{OUT} Separate Type)

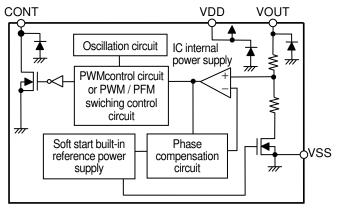


Figure 3

Product Name Structure

The control system, product types, output voltage, and packages for the S-8353/8354 Series can be selected at the user's request. Please refer to the "**3**. **Product Name**" for the definition of the product name, "**4**. **Package**" regarding the package drawings and "**5**. **Product Name List**" for the full product names.

Table 1

1. Function List

(1) PWM Control Products

Product Name	Switching Frequency [kHz]	Shutdown Function	V _{DD} / V _{OUT} Separate Type	Package	Application
S-8353AxxMC	50	Yes	_	SOT-23-5	Applications requiring shutdown function
S-8353AxxMA	50	_	_	SOT-23-3	Applications not requiring shutdown function
S-8353AxxUA	50	_	_	SOT-89-3	Applications not requiring shutdown function
S-8353CxxMA	30	_	_	SOT-23-3	For pager
S-8353CxxUA	30	_	_	SOT-89-3	For pager
S-8353DxxMC	50	_	Yes	SOT-23-5	Applications requiring variable output voltage with an external resistor
S-8353HxxMC	250	Yes	-	SOT-23-5	Applications requiring a shutdown function and a thin coil
S-8353HxxMA	250	_	_	SOT-23-3	Applications not requiring a shutdown function and requiring a thin coil
S-8353HxxUA	250	_	_	SOT-89-3	Applications not requiring a shutdown function and requiring a thin coil
S-8353JxxMC	250	_	Yes	SOT-23-5	Applications requiring variable output voltage with an external resistor and a thin coil

(2) PWM / PFM Switching Control Products

Table 2	2
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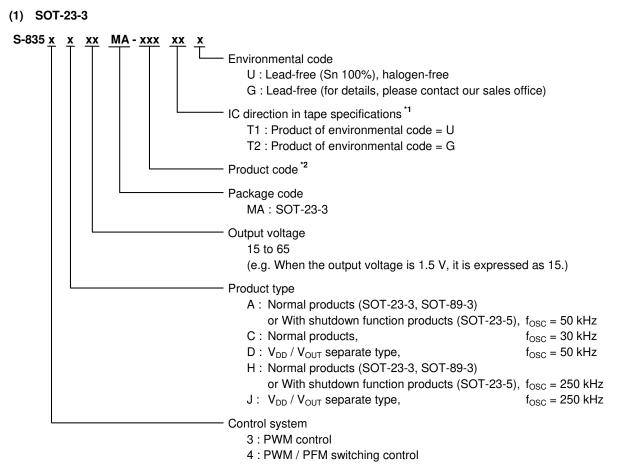
Product Name	Switching Frequency [kHz]	Shutdown Function	V _{DD} / V _{OUT} Separate Type	Package	Application
S-8354AxxMC	50	Yes	-	SOT-23-5	Applications requiring shutdown function
S-8354AxxMA	50	_	_	SOT-23-3	Applications not requiring shutdown function
S-8354AxxUA	50	_	_	SOT-89-3	Applications not requiring shutdown function
S-8354CxxMA	30	_	_	SOT-23-3	For pager
S-8354DxxMC	50	-	Yes	SOT-23-5	Applications requiring variable output voltage with an external resistor
S-8354HxxMC	250	Yes	-	SOT-23-5	Applications requiring a shutdown function and a thin coil
S-8354HxxMA	250	_	-	SOT-23-3	Applications not requiring a shutdown function and requiring a thin coil
S-8354HxxUA	250	-	_	SOT-89-3	Applications not requiring a shutdown function and requiring a thin coil
S-8354JxxMC	250	-	Yes	SOT-23-5	Applications requiring variable output voltage with an external resistor and a thin coil

2. Package and Function List by Product Type

Series Name	Туре	Package Name (Abbreviation)	Shutdown Function Yes / No	V _{DD} / V _{OUT} Separate Type Yes / No
	A (Normal product or with shutdown function) A = 50 kHz	MC MA / UA	Yes No	No
S-8353 Series, S-8354 Series	C (Normal product) C = 30 kHz	MA	No	No
	D (V_{DD} / V_{OUT} separate type) D = 50 kHz	MC	No	Yes
	H (Normal product or with shutdown	MC	Yes	N
	function) H = 250 kHz	MA / UA	No	No
	J (V_{DD} / V_{OUT} separate type) J = 250 kHz	MC	No	Yes

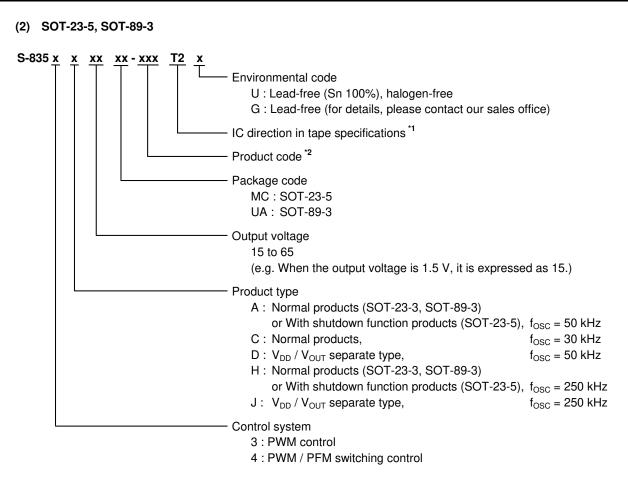
Table 3

3. Product Name



***1.** Refer to the tape specifications.

*2. Refer to the Table 4 to Table 8 in the "5. Product Name List".



*1. Refer to the tape specifications.

*2. Refer to the Table 4 to Table 8 in the "5. Product Name List".

4. Package

Package Name		Drawing Code			
	r ackaye Name	Package	Tape	Reel	
SOT-23-3	Environmental code = G	MP003-A-P-SD	MP003-A-C-SD	MP003-A-R-SD	
301-23-3	Environmental code = U	MP003-C-P-SD	MP003-C-C-SD	MP003-Z-R-SD	
SOT-23-5		MP005-A-P-SD	MP005-A-C-SD	MP005-A-R-SD	
SOT-89-3		UP003-A-P-SD	UP003-A-C-SD	UP003-A-R-SD	

STEP-UP, PWM CONTROL or PWM / PFM SWITCHABLE BUILT-IN TRANSISTOR SWITCHING REGULATOR S-8353/8354 Series Rev.3.0_00

5. Product Name List

(1) S-8353 Series

Table 4

Output voltage	S-8353AxxMC Series	S-8353AxxMA Series	S-8353AxxUA Series	S-8353CxxMA Series
2.0 V	S-8353A20MC-IQFT2x	-	-	-
2.5 V	S-8353A25MC-IQKT2x	_	_	_
2.7 V	S-8353A27MC-IQMT2x	_	_	_
2.8 V	S-8353A28MC-IQNT2x	-	_	-
3.0 V	S-8353A30MC-IQPT2x	S-8353A30MA-IQPTDD	S-8353A30UA-IQPT2x	S-8353C30MA-ISPTDD
3.3 V	S-8353A33MC-IQST2x	S-8353A33MA-IQSTDD	S-8353A33UA-IQST2x	-
3.5 V	S-8353A35MC-IQUT2x	_	_	_
3.6 V	_	_	S-8353A36UA-IQVT2x	_
3.8 V	S-8353A38MC-IQXT2x	_	S-8353A38UA-IQXT2x	_
4.0 V	_	_	S-8353A40UA-IQZT2x	_
4.5 V	S-8353A45MC-IRET2x	_	_	_
4.6 V	_	_	_	S-8353C46MA-ITFTDD
5.0 V	S-8353A50MC-IRJT2x	S-8353A50MA-IRJTDD	S-8353A50UA-IRJT2x	_
5.5 V	S-8353A55MC-IROT2x	_	S-8353A55UA-IROT2x	_

Table 5

Output	S-8353CxxUA	S-8353DxxMC	S-8353HxxMC	S-8353HxxMA
voltage	Series	Series	Series	Series
2.0 V	-	S-8353D20MC-IUFT2x	S-8353H20MC-IWFT2x	-
2.6 V	_	-	S-8353H26MC-IWLT2x	-
2.8 V	-	-	S-8353H28MC-IWNT2x	-
3.0 V	S-8353C30UA-ISPT2x	S-8353D30MC-IUPT2x	S-8353H30MC-IWPT2x	S-8353H30MA-IWPTDD
3.1 V	-	-	S-8353H31MC-IWQT2x	-
3.2 V	_	-	S-8353H32MC-IWRT2x	-
3.3 V	-	-	S-8353H33MC-IWST2x	S-8353H33MA-IWSTDD
3.5 V	-	-	S-8353H35MC-IWUT2x	-
3.7 V	-	-	S-8353H37MC-IWWT2x	_
3.8 V	-	-	S-8353H38MC-IWXT2x	-
4.0 V	-	-	S-8353H40MC-IWZT2x	-
4.5 V	-	-	S-8353H45MC-IXET2x	-
5.0 V	-	S-8353D50MC-IVJT2x	S-8353H50MC-IXJT2x	-
6.0 V	-	_	S-8353H60MC-IXTT2x	-
6.5 V	_	_	S-8353H65MC-IXYT2x	_

Remark 1. Please contact the SII marketing department for products with an output voltage other than those specified above.

2. x: G or U

3. □□: 2G or 1U

4. Please select products of environmental code = U for Sn 100%, halogen-free products.

Table 6

Output voltage	S-8353HxxUA Series	S-8353JxxMC Series
1.8 V	_	S-8353J18MC-IYDT2x
2.0 V	_	S-8353J20MC-IYFT2x
2.1 V	_	S-8353J21MC-IYGT2x
2.5 V	_	S-8353J25MC-IYKT2x
3.0 V	-	S-8353J30MC-IYPT2x
3.3 V	S-8353H33UA-IWST2x	S-8353J33MC-IYST2x
3.6 V	S-8353H36UA-IWVT2x	_
5.0 V	S-8353H50UA-IXJT2x	S-8353J50MC-IZJT2x

(2) S-8354 Series

Table 7

Output voltage	S-8354AxxMC Series	S-8354AxxMA Series	S-8354AxxUA Series	S-8354CxxMA Series
2.0 V	-	S-8354A20MA-JQFTDD	_	-
2.7 V	S-8354A27MC-JQMT2x	S-8354A27MA-JQMTDD	_	-
2.8 V	_	S-8354A28MA-JQNTDD	S-8354A28UA-JQNT2x	-
3.0 V	S-8354A30MC-JQPT2x	S-8354A30MA-JQPTDD	S-8354A30UA-JQPT2x	S-8354C30MA-JSPTDD
3.3 V	S-8354A33MC-JQST2x	S-8354A33MA-JQSTDD	S-8354A33UA-JQST2x	-
3.5 V	-	-	S-8354A35UA-JQUT2x	-
3.8 V	S-8354A38MC-JQXT2x	-	-	-
4.0 V	S-8354A40MC-JQZT2x	-	S-8354A40UA-JQZT2x	-
5.0 V	S-8354A50MC-JRJT2x	S-8354A50MA-JRJTDD	S-8354A50UA-JRJT2x	-

Table 8

Output voltage	S-8354DxxMC Series	S-8354HxxMC Series	S-8354HxxUA Series	S-8354JxxMC Series
1.5 V	-	-	-	S-8354J15MC-JYAT2x
2.0 V	S-8354D20MC-JUFT2x	-	_	S-8354J20MC-JYFT2x
2.5 V	_	S-8354H25MC-JWKT2x	_	-
2.7V	-	S-8354H27MC-JWMT2x	S-8354H27UA-JWMT2x	_
3.0 V	S-8354D30MC-JUPT2x	S-8354H30MC-JWPT2x	_	S-8354J30MC-JYPT2x
3.1 V	_	S-8354H31MC-JWQT2x	_	_
3.3 V	S-8354D33MC-JUST2x	S-8354H33MC-JWST2x	_	S-8354J33MC-JYST2x
3.5 V	-	S-8354H35MC-JWUT2x	_	—
4.0 V	-	S-8354H40MC-JWZT2x	_	_
4.2 V	_	S-8354H42MC-JXBT2x	_	_
4.5 V	_	S-8354H45MC-JXET2x	_	_
4.7 V	_	S-8354H47MC-JXGT2x	_	_
5.0 V	_	S-8354H50MC-JXJT2x	_	S-8354J50MC-JZJT2x

Remark 1. Please contact the SII marketing department for products with an output voltage other than those specified above.

2. x: G or U

3. □□: 2G or 1U

4. Please select products of environmental code = U for Sn 100%, halogen-free products.

Pin Configurations

SOT-23-3 Top view

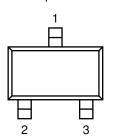


Figure 4

SOT-23-5 Top view

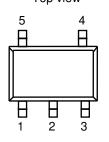


Figure 5

Table 9 A, C and H Types (Without shutdown function, V_{DD} / V_{OUT} non-separate type)

Pin No.	Symbol	Description
1	VOUT	Output voltage pin and IC power supply pin
2	VSS	GND pin
3	CONT	External inductor connection pin

Table 10 A and H Types (With shutdown function, V_{DD} / V_{OUT} non-separate type)

Pin No.	Symbol	Description
1	ON/OFF	Shutdown pin "H": Normal operation (Step-up operating) "L": Step-up stopped (Entire circuit stopped)
2	VOUT	Output voltage pin and IC power supply pin
3	NC ^{*1}	No connection
4	VSS	GND pin
5	CONT	External inductor connection pin

*1. The NC pin indicates electrically open.

Table 11 D and J Types (Without shutdown function, V_{DD} / V_{OUT} separate type)

Symbol	Description
VOUT	Output voltage pin
VDD	IC power supply pin
NC ^{*1}	No connection
VSS	GND pin
CONT	External inductor connection pin
	VOUT VDD NC ^{*1} VSS

*1. The NC pin indicates electrically open.

Table 12 A and H Types

(Without shutdown function, V_{DD} / V_{OUT} non-separate type)

Pin No.	Symbol	Description		
1	VSS	GND pin		
2	VOUT	Output voltage pin and IC power supply pin		
3	CONT	External inductor connection pin		



SOT-89-3

Top view



Figure 6

Table 13

Absolute Maximum Ratings

			$(Ta = 25^{\circ}C \text{ unless otherwise})$	erwise specified)
lt	em	Symbol	Absolute maximum rating	Unit
VOUT pin voltage		V _{OUT}	V_{SS} – 0.3 to V_{SS} + 12	V
ON/OFF pin voltage	je ^{*1}	$V_{ON/\overline{OFF}}$	$V_{\text{SS}} - 0.3$ to $V_{\text{SS}} + 12$	V
VDD pin voltage ^{*2}		V _{DD}	V_{SS} – 0.3 to V_{SS} + 12	V
CONT pin voltage		V _{CONT}	V_{SS} – 0.3 to V_{SS} + 12	V
CONT pin current		I _{CONT}	300	mA
	SOT-23-3		150 (When not mounted on board)	mW
	301-23-3		430 ^{*3}	mW
Dower dissinction		Р	250 (When not mounted on board)	mW
Power dissipation	SOT-23-5	P _D	600 ^{*3}	mW
			500 (When not mounted on board)	mW
	SOT-89-3		1000 ^{*3}	mW
Operating ambient to	emperature	T _{opr}	-40 to + 85	°C
Storage temperature	9	T _{sta}	-40 to + 125	°C

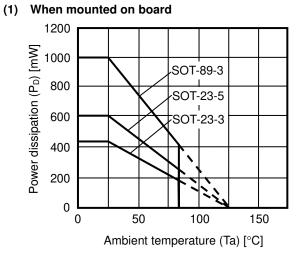
*1. With shutdown function

*2. For V_{DD} / V_{OUT} separate type

*3. When mounted on board

[Mounted board]

- (1) Board size : $114.3 \text{ mm} \times 76.2 \text{ mm} \times t1.6 \text{ mm}$
- (2) Board name : JEDEC STANDARD51-7
- Caution The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.





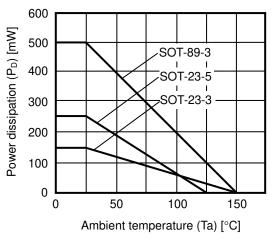


Figure 7 Power Dissipation of Packages

Electrical Characteristics

(1) 50 kHz Product (A and D Types)

Table 14

ltem	Symbol	Condition	n	(T Min.	<u>а = 25°</u> Тур.	C unles Max.	s otherwi Unit	se specified) Measurement circuit
Output voltage	V _{OUT}			$V_{OUT(S)} imes 0.976$	V _{OUT(S)}	$V_{OUT(S)} imes 1.024$	V	2
Input voltage	V _{IN}	_		_	-	10	V	2
Operation start voltage	V _{ST1}	I _{OUT} = 1 mA		-	-	0.9	V	2
Oscillation start voltage	V _{ST2}	No external parts, Voltage	applied to V _{OUT}	_	١	0.8	V	1
Operation holding voltage	V _{HLD}	I _{OUT} = 1 mA, Judged by de voltage gradually	creasing V_{IN}	0.7	_	-	V	2
			S-835xx15 to 19	-	10.8	18.0	μA	1
			S-835xx20 to 29	-	13.3	22.2	μA	1
Current consumption 1		$V_{OUT} = V_{OUT(S)} \times 0.95$	S-835xx30 to 39	-	18.7	31.1	μA	1
Current consumption 1	I _{SS1}	$\mathbf{v}_{\text{OUT}} = \mathbf{v}_{\text{OUT}(S)} \times 0.95$	S-835xx40 to 49	-	24.7	41.1	μA	1
			S-835xx50 to 59	-	31.0	51.6	μA	1
			S-835xx60 to 65	_	37.8	63.0	μA	1
			S-835xx15 to 19	-	4.8	9.5	μA	1
			S-835xx20 to 29	-	5.0	9.9	μA	1
Current consumption 2	I _{SS2}	$V_{OUT} = V_{OUT(S)} + 0.5 V$	S-835xx30 to 39	-	5.1	10.2	μA	1
	1882	V001 - V001(S) + 0.0 V	S-835xx40 to 49	_	5.3	10.6	μA	1
			S-835xx50 to 59	-	5.5	10.9	μA	1
			S-835xx60 to 65	_	5.7	11.3	μA	1
Current consumption during shutdown (With shutdown function)	I _{SSS}	$V_{ON/\overline{OFF}} = 0 V$		-	-	0.5	μA	1
			S-835xx15 to 19	80	128	_	mA	1
			S-835xx20 to 24	103	165	_	mA	1
	I _{SW}		S-835xx25 to 29	125	200	-	mA	1
Switching current		$V_{CONT} = 0.4 V$	S-835xx30 to 39	144	231	-	mA	1
			S-835xx40 to 49	176	282	-	mA	1
			S-835xx50 to 59	200	320	-	mA	1
			S-835xx60 to 65	215	344	_	mA	1
Switching transistor leakage current	I _{SWQ}	$V_{CONT} = V_{OUT} = 10 V$		-	_	0.5	μA	1
Line regulation	ΔV_{OUT1}	$V_{IN} = V_{OUT(S)} \times 0.4 \text{ to } \times 0.6$		-	30	60	mV	2
Load regulation	ΔV_{OUT2}	$I_{OUT} = 10 \mu\text{A}$ to $V_{OUT(S)} / 25$	0×1.25	-	30	60	mV	2
Output voltage temperature coefficient	ΔVουτ ΔTa • Voυτ	Ta = -40°C to +85°C		-	±50	-	ppm / °C	2
Oscillation frequency	f _{OSC}	$V_{OUT} = V_{OUT(S)} \times 0.95$		42.5	50	57.5	kHz	1
Maximum duty ratio	MaxDuty	$V_{OUT} = V_{OUT(S)} \times 0.95$		75	83	90	%	1
PWM / PFM switching duty ratio (For S-8354 Series)	PFMDuty	$V_{IN} = V_{OUT(S)} - 0.1 V$, No-lo	ad	10	15	24	%	1
,,,,,,	V _{SH}	Measured oscillation at CC	ONT pin	0.75	-	-	V	1
ON/OFF pin input voltage	V _{SL1}	Judged oscillation stop at At $V_{OUT} \ge 1.5 V$		_	-	0.3	V	1
(With shutdown function)	V _{SL2}	CONT pin	At V _{OUT} <1.5 V	-	I	0.2	V	1
ON/OFF pin input current	I _{SH}	$V_{ON/\overline{OFF}} = V_{OUT(S)} \times 0.95$		- 0.1	_	0.1	μA	1
(With shutdown function)	I _{SL}	$V_{ON/\overline{OFF}} = 0 V$		- 0.1	-	0.1	μA	1
Soft start time	t _{ss}	-		3.0	6.0	12.0	ms	2
Efficiency	EFFI			-	85		%	2

External parts

- **Remark** 1. V_{OUT(S)} specified above is the set output voltage value, and V_{OUT} is the typical value of the actual output voltage.
 - **2.** V_{DD} / V_{OUT} separate type
 - A step-up operation is performed from $V_{DD} = 0.8 \text{ V}$. However, 1.8 V \leq V_{DD} \leq 10 V is recommended stabilizing the output voltage and oscillation frequency. (V_{DD} \geq 1.8 V must be applied for products with a set value of less than 1.9 V.)

STEP-UP, PWM CONTROL or PWM / PFM SWITCHABLE BUILT-IN TRANSISTOR SWITCHING REGULATOR S-8353/8354 Series Rev.3.0_00

(2) 30 kHz Product (C Type)

		Tabi						
		-		(T	a = 25°	°C unles	s otherw	ise specified
Item	Item Symbol Condition		on	Min.	Тур.	Max.	Unit	Measuremen circuit
Output voltage	V _{OUT}	-		$\begin{array}{c} V_{OUT(S)} \\ \times 0.976 \end{array}$	$V_{\text{OUT}(S)}$	$\begin{array}{c} V_{OUT(S)} \\ \times 1.024 \end{array}$	V	2
Input voltage	V _{IN}	-		-	-	10	V	2
Operation start voltage	V _{ST1}	I _{OUT} = 1 mA		-	-	0.9	V	2
Oscillation start voltage	V _{ST2}	No external parts, Voltag	e applied to V _{OUT}	-	-	0.8	V	1
Operation holding voltage	V _{HLD}	I _{OUT} = 1 mA, Judged by c voltage gradually	lecreasing V_{IN}	0.7	_	-	V	2
			S-835xx20 to 29	-	9.8	16.4	μA	1
			S-835xx30 to 39	-	13.1	21.9	μA	1
Current consumption 1	I _{SS1}	$V_{OUT} = V_{OUT(S)} \times 0.95$	S-835xx40 to 49	_	16.8	28.0	μA	1
			S-835xx50 to 59	-	20.7	34.5	μA	1
			S-835xx60 to 65	_	24.8	41.4	μA	1
			S-835xx20 to 29	-	435	9.0	μA	1
			S-835xx30 to 39	-	4.7	9.4	μA	1
Current consumption 2	2 I _{SS2}	$V_{OUT} = V_{OUT(S)} + 0.5 V$	S-835xx40 to 49	-	4.9	9.7	μA	1
			S-835xx50 to 59	-	5.1	10.1	μA	1
			S-835xx60 to 65	-	5.2	10.4	μA	1
			S-835xx20 to 24	52	83	-	mA	1
		$V_{\text{CONT}} = 0.4 \text{ V}$	S-835xx25 to 29	62	100	-	mA	1
Outitabien europat			S-835xx30 to 39	72	115	-	mA	1
Switching current	I _{SW}		S-835xx40 to 49	88	141	-	mA	1
			S-835xx50 to 59	100	160	-	mA	1
			S-835xx60 to 65	108	172	-	mA	1
Switching transistor leakage current	I _{swa}	$V_{CONT} = V_{OUT} = 10 V$		_	_	0.5	μA	1
Line regulation	ΔV_{OUT1}	$V_{IN} = V_{OUT(S)} \times 0.4$ to $\times 0.4$	6	_	30	60	mV	2
Load regulation			-	30	60	mV	2	
Output voltage temperature coefficient	$\frac{\Delta V_{OUT}}{\Delta Ta \bullet V_{OUT}}$	$Ta = -40^{\circ}C \text{ to } +85^{\circ}C$		-	±50	-	ppm / °C	2
Oscillation frequency	f _{OSC}	$V_{OUT} = V_{OUT(S)} \times 0.95$		25	30	35	kHz	1
Maximum duty ratio	MaxDuty	$V_{OUT} = V_{OUT(S)} \times 0.95$		75	83	90	%	1
PWM / PFM switching duty ratio (For S-8354 Series)	PFMDuty	$V_{IN} = V_{OUT(S)} - 0.1 V$, No-	load	10	15	24	%	1
Soft start time	t _{SS}	-		3.0	6.0	12.0	ms	2
Efficiency	EFFI	_		_	84	_	%	2

Table 15

External parts

Coil: CDRH6D28-101 of Sumida Corporation

Diode: MA2Z748 (Shottky type) of Matsushita Electric Industrial Co., Ltd.

Capacitor: F93 (16 V, 22 μ F tantalum type) of Nichicon Corporation

 V_{IN} = $V_{\text{OUT}(S)} \times$ 0.6 applied, I_{OUT} = $V_{\text{OUT}(S)}$ / 250 Ω

Remark V_{OUT(S)} specified above is the set output voltage value, and V_{OUT} is the typical value of the actual output voltage.

STEP-UP, PWM CONTROL or PWM / PFM SWITCHABLE BUILT-IN TRANSISTOR SWITCHING REGULATOR Rev.3.0_00 S-8353/8354 Series

(3) 250 kHz Product (H and J Types)

		Table	16	(Т	a = 25°	°C unles	s otherw	ise specified)
ltem	Symbol	Conditio	n	Min.	Тур.	Max.	Unit	Measurement circuit
Output voltage	V _{OUT}	_		$\begin{array}{c} V_{OUT(S)} \\ \times 0.976 \end{array}$	V _{OUT(S)}	$\begin{array}{c} V_{OUT(S)} \\ \times 1.024 \end{array}$	V	2
Input voltage	V _{IN}	-		-	-	10	V	2
Operation start voltage	V _{ST1}	I _{OUT} = 1 mA		-	-	0.9	V	2
Oscillation start voltage	V _{ST2}	No external parts, Voltage	11 991	-	-	0.8	V	1
Operation holding voltage	V _{HLD}	I _{OUT} = 1 mA, Judged by de voltage gradually	ecreasing V _{IN}	0.7	-	-	V	2
			S-835xx15 to 19	-	36.5	60.8	μA	1
			S-835xx20 to 29	-	48.3	80.5	μA	1
Current consumption 1	I _{SS1}	$V_{OUT} = V_{OUT(S)} \times 0.95$	S-835xx30 to 39	-	74.3	123.8	μA	1
ourion concumption 1	'551	•001 - •001(S) × 0.00	S-835xx40 to 49	-	103.1	171.9	μA	1
			S-835xx50 to 59	-	134.1	223.5	μA	1
			S-835xx60 to 65	-	167.0	278.4	μA	1
			S-835xx15 to 19	-	9.1	18.2	μA	1
			S-835xx20 to 29	-	9.3	18.6	μA	1
Current consumption 2		$V_{OUT} = V_{OUT(S)} + 0.5 V$	S-835xx30 to 39	-	9.5	18.9	μA	1
	I _{SS2}	•001 - •001(S) + 0.5 •	S-835xx40 to 49	-	9.7	19.3	μA	1
			S-835xx50 to 59	-	9.8	19.6	μA	1
			S-835xx60 to 65	-	10.0	19.9	μA	1
Current consumption during shutdown (With shutdown function)	I _{SSS}	$V_{ON/OFF} = 0 V$		-	_	0.5	μΑ	1
			S-835xx15 to 19	80	128	_	mA	1
			S-835xx20 to 24	103	165	_	mA	1
			S-835xx25 to 29	125	200	_	mA	1
Switching current	I _{SW}	$V_{CONT} = 0.4 V$	S-835xx30 to 39	144	231	_	mA	1
0	.311	JON	S-835xx40 to 49	176	282	_	mA	1
			S-835xx50 to 59	200	320	_	mA	1
			S-835xx60 to 65	215	344	_	mA	1
Switching transistor leakage current	I _{SWQ}	V _{CONT} = V _{OUT} = 10 V		-	_	0.5	μA	1
Line regulation	ΔV_{OUT1}	$V_{IN} = V_{OUT(S)} \times 0.4$ to $\times 0.6$		_	30	60	mV	2
Load regulation	ΔV_{OUT2}	$I_{OUT} = 10 \mu\text{A to } V_{OUT(S)} / 25$		_	30	60	mV	2
Output voltage temperature coefficient			_	±50	-	ppm / °C	2	
Oscillation frequency	f _{OSC}	$V_{OUT} = V_{OUT(S)} \times 0.95$		212.5	250	287.5	kHz	1
Maximum duty ratio				70	78	85	%	1
PWM / PFM switching duty ratio (For S-8354 Series)	PFMDuty	$V_{\text{OUT}} = V_{\text{OUT}(S)} \times 0.95$ $V_{\text{IN}} = V_{\text{OUT}(S)} - 0.1 \text{ V, No-load}$		10	15	24	%	1
· · · · · · · · · · · · · · · · · · ·	V _{SH}	Measured oscillation at CONT pin		0.75	_	_	V	1
ON/OFF pin input voltage	V _{SL1}	Judged oscillation stop at	At V _{OUT} ≥1.5 V	_	_	0.3	V	1
(With shutdown function)	V _{SL2}	CONT pin	At V _{OUT} <1.5 V	_	_	0.2	V	1
ON/OFF pin input current	I _{SH}	$V_{ON/\overline{OFF}} = V_{OUT(S)} \times 0.95$		- 0.1	_	0.1	μA	1
(With shutdown function)	I _{SL}	$V_{ON/OFF} = 0 V$		- 0.1	-	0.1	μA	1
Soft start time	t _{ss}	_		1.8	3.6	7.2	ms	2
Efficiency	EFFI			-	85	_	%	2

External parts

Coil: CDRH6D28-220 of Sumida Corporation Diode: MA2Z748 (Shottky type) of Matsushita Electric Industrial Co., Ltd.

Capacitor: F93 (16 V, 22 μ F tantalum type) of Nichicon Corporation

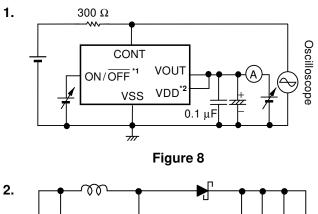
 $V_{IN} = V_{OUT(S)} \times 0.6$ applied, $I_{OUT} = V_{OUT(S)} / 250 \Omega$

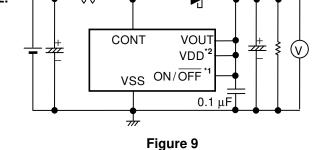
With shutdown function : ON/\overline{OFF} pin is connected to V_{OUT}

For V_{DD} / V_{OUT} separate type : VDD pin is connected to VOUT pin

- **Remark** 1. V_{OUT(S)} specified above is the set output voltage value, and V_{OUT} is the typical value of the actual output voltage.
 - **2.** V_{DD} / V_{OUT} separate type
 - A step-up operation is performed from $V_{DD} = 0.8 \text{ V}$. However, 1.8 V \leq V_{DD} \leq 10 V is recommended stabilizing the output voltage and oscillation frequency. (V_{DD} \geq 1.8 V must be applied for products with a set value of less than 1.9 V.)

Measurement Circuits





- *1. With shutdown function
- *2. For V_{DD} / V_{OUT} separate type

Operation

1. Switching Control Types

1.1 PWM Control (S-8353 Series)

The S-8353 Series is a DC-DC converter using a pulse width modulation method (PWM) and features low current consumption. In conventional PFM DC-DC converters, pulses are skipped when the output load current is low, causing a fluctuation in the ripple frequency of the output voltage, resulting in an increase in the ripple voltage. In the S-8353 Series, the switching frequency does not change, although the pulse width changes from 0% to 83% (78% for H and J type) corresponding to each load current. The ripple voltage generated from switching can thus be removed easily using a filter because the switching frequency is constant.

1.2 PWM / PFM Switching Control (S-8354 Series)

The S-8354 Series is a DC-DC converter that automatically switches between a pulse width modulation method (PWM) and a pulse frequency modulation method (PFM), depending on the load current, and features low current consumption.

The S-8354 Series operates under PWM control with the pulse width duty changing from 15% to 83% (78% for H and J type) in a high output load current area. On the other hand, the S-8354 Series operates under PFM control with the pulse width duty fixed at 15% in a low output load current area, and pulses are skipped according to the load current. The oscillation circuit thus oscillates intermittently so that the resultant lower self current consumption can prevent a reduction in the efficiency at a low load current. The switching point from PWM control to PFM control depends on the external devices (coil, diode, etc.), input voltage, and output voltage. This series are an especially efficient DC-DC converter at an output current around 100 μ A.

2. Soft Start Function

For this IC, a built-in soft start circuit controls the rush current and overshoot of the output voltage when the power is turned on or the ON/\overline{OFF} pin is set to "H" level.

3. ON/OFF Pin (Shutdown Pin) (SOT-23-5 Package Products of A and H Types)

 ON/\overline{OFF} pin stops or starts step-up operation.

Setting the ON/\overline{OFF} pin to the "L" level stops operation of all the internal circuits and reduces the current consumption significantly.

DO NOT use the ON/\overline{OFF} pin in a floating state because it has the structure shown in **Figure 10** and is not pulled up or pulled down internally. DO NOT apply a voltage of between 0.3 V and 0.75 V to the ON/\overline{OFF} pin because applying such a voltage increases the current consumption. If the ON/\overline{OFF} pin is not used, connect it to the VOUT pin.

The ON/OFF pin does not have hysteresis.

ON/OFF pin	CR oscillation circuit	Output voltage		
"H"	Operation	Fixed		
"L"	Stop	≅V _{IN} *1		

*1. Voltage obtained by subtracting the voltage drop due to the DC resistance of the inductor and the diode forward voltage from V_{IN}.

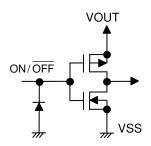


Figure 10 ON/OFF Pin Structure

4. Operation

The following are the basic equations [(1) through (7)] of the step-up switching regulator. (Refer to Figure 11.)

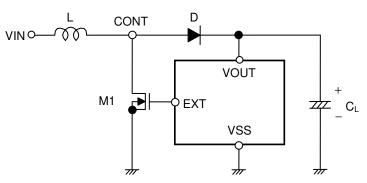


Figure 11 Step-Up Switching Regulator Circuit for Basic Equation

Voltage at CONT pin at the moment M1 is turned ON (V _A) ^{*1} : V _A = V _S ^{*2} *1. Current flowing through L (I _L) is zero. *2. Non-saturated voltage of M1.	(1)
The change in I _L over time : $\frac{dI_L}{dt} = \frac{V_L}{L} = \frac{V_{IN} - V_S}{L}$	(2)
Integration of equation (2) (I _L) : $I_{L} = \left(\frac{V_{IN} - V_{S}}{L}\right) \bullet t$	(3)
$\begin{split} I_L & \text{flows while M1 is ON } (t_{\text{ON}}). & \text{The time of } t_{\text{ON}} \text{ is determined by the oscillation frequency of OSC.} \\ & \text{The peak current } (I_{\text{PK}}) \text{ after } t_{\text{ON}} : \\ & I_{\text{PK}} = & \left(\frac{V_{\text{IN}} - V_{\text{S}}}{L} \right) \bullet t_{\text{ON}} \end{split}$	(4)
The energy stored in L is represented by 1/2 • L $(I_{PK})^2$. When M1 is turned OFF (t_{OFF}) , the energy stored in L is emitted through a diode to the output capacitor. Then, the reverse voltage (V_L) is generated : $V_L = (V_{OUT} + V_D^{*1}) - V_{IN}$ *1. Diode forward voltage	(5)
The voltage at CONT pin rises only by $V_{OUT}+V_D$. The change in the current (I _L) flowing through the diode into V_{OUT} during t_{OFF} : dI _L V _L V _{OUT} + V _D - V _{IN}	(6)

<u>_</u>	<u>11_</u> _	<u></u> =	$v_{OUT} + v_D - v_{IN}$	(6)
(dt	L	L	 (0)

Integration of the equation (6) is as follows :

$$I_{L} = I_{PK} - \left(\frac{V_{OUT} + V_{D} - V_{IN}}{L}\right) \bullet t$$
(7)

During t_{ON} , the energy is stored in L and is not transmitted to V_{OUT} . When receiving the output current (I_{OUT}) from V_{OUT} , the energy of the capacitor (C_L) is consumed. As a result, the pin voltage of C_L is reduced, and goes to the lowest level after M1 is turned ON (t_{ON}). When M1 is turned OFF, the energy stored in L is transmitted through the diode to C_L , and the voltage of C_L rises rapidly. V_{OUT} is a time function, and therefore indicates the maximum value (ripple voltage (V_{P-P})) when the current flowing through into V_{OUT} and load current (I_{OUT}) match. Next, the ripple voltage is determined as follows.

 I_{OUT} vs. t_1 (time) from when M1 is turned OFF (after t_{ON}) to when V_{OUT} reaches the maximum level :

$$I_{OUT} = I_{PK} - \left(\frac{V_{OUT} + V_D - V_{IN}}{L}\right) \bullet t_1$$

$$\therefore t_1 = (I_{PK} - I_{OUT}) \bullet \left(\frac{L}{V_{OUT} + V_D - V_{IN}}\right)$$
(8)
(9)

When M1 is turned OFF (t_{OFF}), $I_L = 0$ (when the energy of the inductor is completely transmitted). Based on equation (7) :

$$\left(\frac{L}{V_{OUT} + V_D - V_{IN}}\right) = \frac{t_{OFF}}{l_{PK}} \quad (10)$$

When substituting equation (10) for equation (9) :

$$t_1 = t_{OFF} - \left(\frac{I_{OUT}}{I_{PK}}\right) \bullet t_{OFF} \quad$$
(11)

Electric charge ΔQ_1 which is charged in C_L during t₁ :

$$\Delta Q_{1} = \int_{0}^{t1} I_{L} dt = I_{PK} \bullet \int_{0}^{t1} dt - \frac{V_{OUT} + V_{D} - V_{IN}}{L} \bullet \int_{0}^{t1} t dt = I_{PK} \bullet t_{1} - \frac{V_{OUT} + V_{D} - V_{IN}}{L} \bullet \frac{1}{2} t_{1}^{2}$$
(12)

When substituting equation (12) for equation (9) :

$$\Delta Q1 = I_{PK} - \frac{1}{2} (I_{PK} - I_{OUT}) \bullet t_1 = \frac{I_{PK} + I_{OUT}}{2} \bullet t_1$$
(13)

A rise in voltage (V_{P-P}) due to ΔQ_1 :

$$V_{P-P} = \frac{\Delta Q_1}{C_L} = \frac{1}{C_L} \bullet \left(\frac{I_{PK} + I_{OUT}}{2} \right) \bullet t_1 \quad \dots$$
(14)

When taking into consideration I_{OUT} to be consumed during t₁ and the Equivalent Series Resistance (R_{ESR}) of C_L :

$$V_{P-P} = \frac{\Delta Q_1}{C_L} = \frac{1}{C_L} \bullet \left(\frac{I_{PK} + I_{OUT}}{2}\right) \bullet t1 + \left(\frac{I_{PK} + I_{OUT}}{2}\right) \bullet R_{ESR} - \frac{I_{OUT} \bullet t_1}{C_L} \quad (15)$$

When substituting equation (11) for equation (15) :

$$V_{P-P} = \frac{(I_{PK} - I_{OUT})^2}{2I_{PK}} \bullet \frac{t_{OFF}}{C_L} + \left(\frac{I_{PK} + I_{OUT}}{2}\right) \bullet R_{ESR}$$
(16)

Therefore to reduce the ripple voltage, it is important that the capacitor connected to the output pin has a large capacity and a small R_{ESR}.

External Parts Selection

The relationship between the major characteristics of the step-up circuit and the characteristic parameters of the external parts is shown in **Figure 12**.

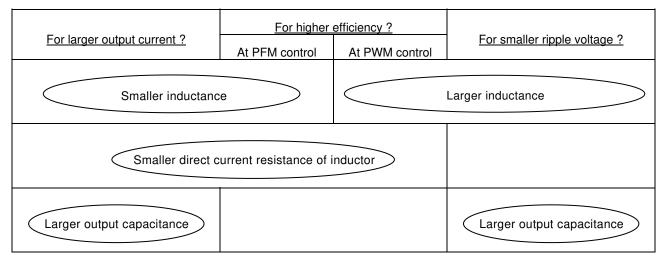


Figure 12 Relationship between Major Characteristics of Step-up Circuit and External Parts

1. Inductor

The inductance value (L value) has a strong influence on the maximum output current (I_{OUT}) and efficiency (η). The peak current (I_{PK}) increases by decreasing L value and the stability of the circuit improves and I_{OUT} increases. If L value is decreased, the efficiency falls causing a decline in the current drive capacity for the switching transistor, and I_{OUT} decreases.

The loss of I_{PK} by the switching transistor decreases by increasing L and the efficiency becomes maximum at a certain L value. Further increasing L value decreases the efficiency due to the loss of the direct current resistance of the coil. I_{OUT} also decreases.

A higher oscillation frequency allows selection of a lower L value, making the coil smaller.

The recommended inductances are a 47 μ H to 220 μ H for A, C, and D types, a 10 μ H to 47 μ H for H and J types. Be careful of the allowable inductor current when choosing an inductor. Exceeding the allowable current of the inductor causes magnetic saturation, much lower efficiency and destruction of the IC chip due to a large current. Choose an inductor so that I_{PK} does not exceed the allowable current. I_{PK} in discontinuous mode is calculated by the following equation:

$$I_{PK} = \sqrt{\frac{2 I_{OUT} (V_{OUT} + V_D - V_{IN})}{f_{OSC} \bullet L}} \quad (A)$$
(17)

 f_{osc} = oscillation frequency, $V_D \cong 0.4 V$.

2. Diode

Use an external diode that meets the following requirements :

- Low forward voltage : $V_F < 0.3 V$
- High switching speed : 50 ns max.
- Reverse voltage : $V_{OUT} + V_F$ or more
- Current rate : I_{PK} or more

3. Capacitor (C_{IN}, C_L)

A capacitor on the input side (C_{IN}) improves the efficiency by reducing the power impedance and stabilizing the input current. Select a C_{IN} value according to the impedance of the power supply used.

A capacitor on the output side (C_L) is used for smoothing the output voltage. For step-up types, the output voltage flows intermittently to the load current, so step-up types need a larger capacitance than step-down types. Therefore, select an appropriate capacitor in accordance with the ripple voltage, which increases in case of a higher output voltage or a higher load current. The capacitor value should be 10 μ F or more.

Select an appropriate capacitor the equivalent series resistance (R_{ESR}) for stable output voltage. The stable voltage range in this IC depends on the R_{ESR} . Although the inductance value (L value) is also a factor, an R_{ESR} of 30 to 500 m Ω maximizes the characteristics. However, the best R_{ESR} value may depend on the L value, the capacitance, the wiring, and the applications (output load). Therefore, fully evaluate the R_{ESR} under the actual operating conditions to determine the best value.

Refer to the "1. Example of Ceramic Capacitor Application" (Figure 16) in the "■ Application Circuit" for the circuit example using a ceramic capacitor and the external resistance of the capacitor (R_{ESR}).

4. V_{DD} / V_{OUT} Separate Type (D and J Types)

The D and J types provides separate internal circuit power supply (VDD pin) and output voltage setting pin (VOUT pin) in the IC, making it ideal for the following applications.

- (1) When changing the output voltage with external resistance.
- (2) When outputting a high voltage within the operating voltage (10 V).

Choose the products in the Table 18 according to the applications (1) or (2) above.

Output voltage (V _{CC})	$1.8 \text{ V} \le \text{V}_{\text{CC}} < 5 \text{ V}$	$5 \text{ V} \le \text{V}_{\text{CC}} \le 10 \text{ V}$
S-835xx18	Yes	_
S-835xx50	-	Yes
Connection to VDD pin	V_{IN} or V_{CC}	V _{IN}

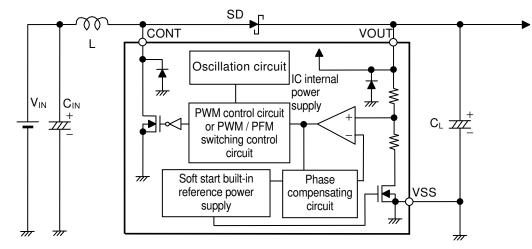
Table 18

- Cautions 1. This IC starts a step-up operation at $V_{DD} = 0.8 \text{ V}$, but set $1.8 \le V_{DD} \le 10 \text{ V}$ to stabilize the output voltage and frequency of the oscillator. (Input a voltage of 1.8 V or more at the VDD pin for all products with a setting less than 1.9 V.) An input voltage of 1.8 V or more at the VDD pin allows connection of the VDD pin to either the input voltage VIN pin or output VOUT pin.
 - 2. Choose external resistors R_A and R_B so as to not affect the output voltage, considering that there is impedance between the VOUT pin and VSS pin in the IC chip. The internal resistance between the VOUT pin and VSS pin is as follows :
 - (1) S-835xx18 : 2.1 MΩ to 14.8 MΩ
 - (2) S-835xx20 : 1.4 M Ω to 14.8 M Ω
 - (3) S-835xx30 : 1.4 M Ω to 14.2 M Ω
 - (4) S-835xx50 : 1.4 MΩ to 12.1 MΩ
 - 3. Attach a capacitor (C_c) in parallel to the R_A resistance when an unstable event such as oscillation of the output voltage occurs. Calculate C_c using the following equation :

$$C_{c}[F] = \frac{1}{2 \bullet \pi \bullet R_{A} \bullet 20 \text{ kHz}}$$

Standard Circuits

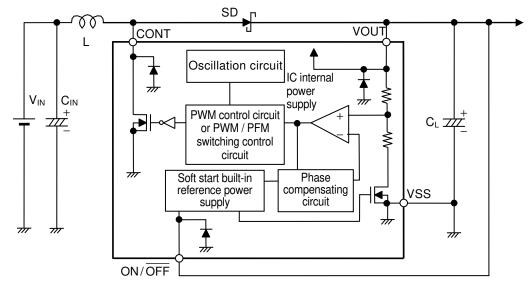
(1) S-8353AxxMA / UA, S-8353CxxMA, S-8353HxxMA/UA, S-8354AxxMA/UA, S-8354CxxMA, S-8354HxxMA / UA



Remark The power supply for the IC chip is from the VOUT pin.

Figure 13

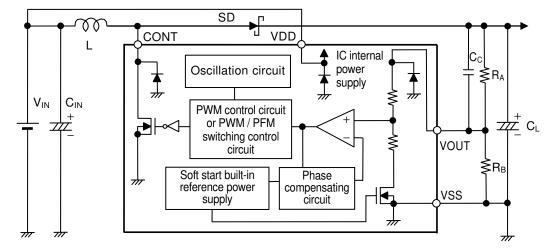
(2) S-8353AxxMC, S-8353HxxMC, S-8354AxxMC, S-8354HxxMC



Remark The power supply for the IC chip is from the VOUT pin.

Figure 14

(3) S-8353DxxMC, S-8353JxxMC, S-8354DxxMC, S-8354JxxMC



Remark The power supply for the IC chip is from the VOUT pin.

Figure 15

Caution The Above connection diagram will not guarantee successful operation. Perform through evaluation using the actual application to set the constant.

Precautions

- Mount external capacitors, diodes, and coils as close as possible to the IC. Especially, mounting the output capacitor (capacitor between VDD pin and VSS pin for V_{DD} / V_{OUT} separate type) in the power supply line of the IC close to the IC can enable stable output characteristics. If it is impossible, it is recommended to mount and wire a ceramic capacitor of around 0.1 μ F close to the IC.
- Characteristics ripple voltage and spike noise occur in IC containing switching regulators. Moreover rush current flows at the time of a power supply injection. Because these largely depend on the coil, the capacitor and impedance of power supply used, fully check them using an actually mounted model.
- Make sure that the dissipation of the switching transistor (especially at a high temperature) does not exceed the allowable power dissipation of the package.
- The performance of this IC varies depending on the design of the PCB patterns, peripheral circuits and external parts. Thoroughly test all settings with your device. The recommended external part should be used wherever possible, but if this is not possible for some reason, contact an SII sales person.
- Do not apply an electrostatic discharge to this IC that exceeds the performance ratings of the built-in electrostatic protection circuit.
- SII claims no responsibility for any and all disputes arising out of or in connection with any infringement of the products including this IC upon patents owned a third party.

Application Circuits

1. Using Ceramic Capacitor Example

When using small R_{ESR} parts such as ceramic capacitors for the output capacitance, mount a resistor (R_1) corresponding to the R_{ESR} in series with the ceramic capacitor (C_L) as shown in **Figure 16**.

 R_1 differs depending on L value, the capacitance, the wiring, and the application (output load).

The following example shows a circuit using $R_1 = 100 \text{ m}\Omega$, output voltage = 3.3 V, output load = 100 mA and its characteristics.

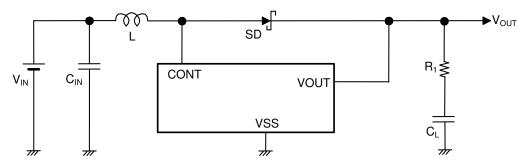


Figure 16 Using Ceramic Capacitor Circuit Example

IC	L Type Name	SD Type Name	C _L (Ceramic capacitor)	R ₁
S-8353A33	CDRH5D28-101	MA2Z748	10 μ F $ imes$ 2	100 m Ω

Caution The Above connection diagram and constant will not guarantee successful operation. Perform through evaluation using the actual application to set the constant.